ELSEVIER

Contents lists available at ScienceDirect

Electrochimica Acta

journal homepage: www.elsevier.com/locate/electacta



Antimony (IV) Oxide Nanorods/Reduced Graphene Oxide as the Anode Material of Sodium-ion Batteries with Excellent Electrochemical Performance



Gui-Zhi Wang, Jian-Min Feng*, Lei Dong, Xi-Fei Li, De-Jun Li*

Energy and Materials Engineering Center, Institute of Physics and Materials Science, Tianjin Normal University, Extension of Bin Shui West Road 393, Xi Qing District, Tianjin 300387, PR China

ARTICLE INFO

Article history:
Received 3 December 2016
Received in revised form 17 April 2017
Accepted 18 April 2017
Available online 20 April 2017

Keywords: Sb₂O₄ Reduced graphene oxide Nanorods Sodium ion batteries

ABSTRACT

Sodium-ion batteries (SIBs) have attracted lots of significant interests, arising from in regard to the development of developing a low-cost energy storage system for renewable energy. Antimony-based materials with that have high theoretical storage capacities of Na⁺ have become one of the most focused SIB anode materials. Among of which, Sb₂O₄ has a higher and thus superior Na⁺ storage capacity of 1227 mAh g⁻¹ compared to other antinomy-based materials. In this work, one simple solvothermal process has been developed to prepare Sb₂O₄/reduced graphene oxide (Sb₂O₄/RGO) composites with a nanostructure of Sb₂O₄ nanorods anchored on RGO. Sb₂O₄/RGO shows an obviously enhanced electrochemical performance with an initial Na⁺ storage capacity of 842 ± 5 mAh g⁻¹, a rechargeable capacity of 551 ± 5 mAh g⁻¹ at 50 mA g⁻¹ after 100 cycles and an excellent rate performance of 401 ± 5 mAh g⁻¹ at 1 A g⁻¹.

© 2017 Elsevier Ltd. All rights reserved.

1. Introduction

The sodium-ion battery (SIB) has attracted lots of significant interests driven by the increasing demand for renewable energy storage systems [1–4]. The energy storage mechanism of the SIB is the same as that of the lithium-ion battery (LIB), both of which depend on an ion rocking-chair process between the anode and cathode [5–10]. However, Na⁺ has a larger ionic size than lithium, which will lead to an intercalation/deintercalation difficulty [11-13] and a larger volume change [14,15]. It means that welldeveloped LIB electrode materials can not be used in a SIB directly [14]. To bridge this gap, the development of electrode materials for SIBs has become a hot topic [16,17]. Inspired by LIB development, different types of electrode materials have been explored for SIBs, including carbon-based materials [18], such as hard carbon [19], carbon nanowires [20], carbon nanofibers [21], hollow carbon [22] and carbon spheres [23], as well as titanium-based compounds [24], such as sodium titanate [25] and titanium oxide [18], alloys of tin/tin oxide [20,26], antimony/antimony oxide [27,28], phosphorus [29,30], organic compounds [31], among others.

Among of these, antimony-based materials have attracted more interests due to their stable Na+ anode storage reaction and high Na⁺ storage capability ability [32,33]. Like a high capacity LIB anode, the large volume change resulting from the process of amounts of Na⁺ intercalation/deintercalation is still an obstacle to the development of high-performance antimony-based SIB anode materials [34,35]. To address this problem, a compositing strategy has been adopted and proven to be effective [36,37]. Nanocomposites of Sb/carbon fibers [38], Sb/carbon black [22], Sb/ porous carbon [19], Sb/carbon microspheres [23], Sb/carbon/ graphene [1], Sb/reduced graphene oxide (RGO) [39] and others have been developed and have shown enhanced performances. In addition, some non-crystallized antimony-based materials have also been fabricated for SIB anodes, including Sb₂O₃/Sb nanoparticles prepared by microwave plasma irradiation [28], Sb₂O₄ thin films prepared by a magnetron sputtering method [40], and so on. Antimony-based SIB anode materials strongly depend on their composite phase and microstructures [41]. Optimized exploration of the composite phase and antimony-based material morphology is an effective means of further developing high-performance antimony-based SIB anodes.

The carbon composite phase could not only buffer the volume change, but also enhance the electrode's electrical conductivity [42,43]. According to the above analysis, a combining strategy of combining nanocrystallization and compositing should be helpful

^{*} Corresponding authors. E-mail addresses: fjmtjun@gmail.com (J.-M. Feng), dli1961@163.com (D.-J. Li).

for the development of high-performance SIB anodes. In an early study, Zhou et al. [9] applied Sb₂O₄ for use in LIBs. They used Sb₂O₃ and graphene oxide to synthesize Sb₂O₄/rGO by a simple solvothermal method. The composite had a steady structure of Sb₂O₄ nanoparticles that was uniformly anchored on rGO sheets. When applied as the LIB anode, it delivered much a better cyclability of 798 mAh g^{-1} at a current density of 100 mA g^{-1} after 200 cycles. Based on the superb performance of LIBs, we could foresee that Sb₂O₄ could meet the requirements of SIBs. Herein. Sb₂O₄ is explored for use in SIB anodes, and reduced graphene oxide is used as the composite phase [37,44]. Sb₂O₄ has a higher theoretical capacity of $1227 \, \text{mAh} \, \text{g}^{-1}$, which is almost twice as that of pure Sb metal $(660 \,\mathrm{mAh}\,\mathrm{g}^{-1})$ [45–47]. Moreover, graphene has shown beneficial properties for the composite [33,48,49]. The combination of Sb₂O₄ and graphene should be feasible for fabricating SIB anodes with enhanced electrochemical perfor-

A two-step controllable process consisting of nanocrystallization and compositing was developed to prepare Sb₂O₄/RGO composites. First, nanocrystallized Sb₂O₄ exhibiting nanorod morphology was prepared by a hydrothermal process. The nanorod morphology should contribute to the enhancement of the electrochemical Na⁺ storage manifestation and should also avoid the large volume change during the long-repeating cycling process [50]. Then, Sb₂O₄/RGO with a hybrid nanostructure of Sb₂O₄ nanorods anchored on RGO was prepared by a simple liquid compositing process. Electrochemical tests showed that there was an impressive composite synergistic effect of the Sb₂O₄ nanorods anchored on the surface of RGO. The Sb₂O₄/RGO anode had an excellent electrochemical performance, showing a stable Na+ storage capacity of $551 \pm 5 \,\mathrm{mAh}\,\mathrm{g}^{-1}$ after 100 cycles and a rate capability of $401 \pm 5 \,\text{mAh}\,\text{g}^{-1}$ at $1 \,\text{A}\,\text{g}^{-1}$. In comparison, the Na⁺ storage capacity of bare Sb₂O₄ was under 100 mAh g⁻¹ after 100 cycles.

2. Experimental

2.1. Synthesis of Sb₂O₄/RGO

GO was first synthesized by a modified Hummers' method [51]. The Sb₂O₄/RGO nanocomposite was synthesized by a simple solvothermal method. First, 0.004 mol of SbCl₃ and 0.02 mol of I₂ were dissolved in 40 mL of deionized water. After ultrasonic processing for nearly 20 minutes, the mixing solution was placed in an autoclave and heated to 180 °C for 20 h. Sb₂O₄ nanorods were prepared by filtration, washed with distilled water several times and dry processed at 80 °C overnight. Second, 50 mg of GO was added into 40 mL of deionized water and then ultrasonically treated for 0.5 h. As-prepared Sb₂O₄ (0, 50, 100 and 200 mg) was mixed with the GO solution, separately (labelled as RGO, Sb₂O₄/RGO-I, Sb₂O₄/RGO-II and Sb₂O₄/RGO-III). Then the-obtained solution was placed in an autoclave and heated to 180 °C for 24 h. The final products were collected by filtration, washed with deionized water and dried at 80 °C for 12 h.

2.2. Materials characterizations

The phase of the final products was characterized by X-ray diffraction (XRD, DX-2700), with Cu/Ka radiation in the range from 10° to 80° and Raman spectroscopy (Raman, LabRAM HR800) from $100-2000\,\mathrm{cm}^{-1}$. Energy dispersive electron microscopy (EDS) measurements were recorded under 20 KV. The morphology of the products was checked by using scanning electron microscopy (SEM, SU8010, Hitachi) and transmission electron microscopy (TEM, JEOL JEM-3000F). Thermogravimetric analysis (TGA, MET-TLER-TOLEDO TGA/DSC1) of the Sb₂O₄/RGO composites was also

conducted from room temperature to $1000\,^{\circ}\text{C}$ at a heating rate of $10\,^{\circ}\text{C}$ per minute in $50\,\text{sccm}$ of flowing air.

2.3. Electrochemical Measurements

The electrochemical properties of the Sb₂O₄/RGO composites were evaluated by assembling 2032 coin cells in a glove box filled with argon (oxygen and moisture < 0.1 ppm). Sodium metal foil was used as the counter electrode, and 1 mol/L NaClO₄ was dissolved in ethylene carbonate and dimethyl carbonate (3:7 by volume) with 5% fluoroethylene carbonate as the electrolyte. The working electrode contained 75 wt.% active materials, 15 wt.% carbon black and 10 wt.% polyvinylidene fluoride (PVDF); N methyl pyrrolidone (NMP) was then used to form a slurry. The electrode was prepared by casting the slurry onto copper foil and drying at 80 °C overnight under vacuum. Next, electrode slices were cut at 12-mm diameter per disks. The weights of the active materials used from both the bare and composite samples were 1.0 mg cm⁻² for every disk. The galvanostatic charge/discharge test was conducted on a LAND cycle (LANHE CT2001A) between 0.01 to 3 V vs Na⁺/Na at room temperature. Cyclic Voltammogram (CV) and Electrochemical Impedance Spectroscopy (EIS) measurements were performed via a Princeton Applied Research VersaSTAT4. The CV measurement was recorded at a scan rate of 0.1 mV s⁻¹ in the range of 0.01-3.0 V vs Na⁺/Na and the EIS was conducted in the range from 100 kHz to 0.01 Hz with an amplitude of 5 mV.

3. Results and discussion

Sb₂O₄/RGO nanocomposites were synthesized by a simple solvothermal process from SbCl₃, I₂ and GO in an aqueous solution. The XRD patterns of Sb₂O₄/RGO-I, Sb₂O₄/RGO-II, and Sb₂O₄/RGO-III, which had patterns of bare Sb₂O₄, RGO and GO within the theta range between 10° and 80° for comparison, are shown in Fig. 1a. The Sb₂O₄ peaks (PDF#78-2066) can be clearly observed in the XRD patterns of the Sb₂O₄/RGO composites and the bare Sb₂O₄. The characteristic diffraction peaks were at approximately 25.5, 29.0, 33.2, 37.0, 45.6, 48.7, 53.4 and 62.6 degrees, belonging to the (011), (100), (112), (120), (024), (310), (026) and (230) reflections of Sb₂O₄, respectively. These characteristic diffraction peaks indicated that the Sb₂O₄ crystalline phase had been obtained. One wide peak at 2theta = 25° of RGO, overlaps with reflection of Sb₂O₄ in the Sb₂O₄/RGO composites. In addition, a sharp and intense peak for GO was observed at 2theta = 10.4°, which disappeared on the pattern of the Sb₂O₄/RGO composites. The disappearance of the peak at 2theta = 10.4° showed that GO had been reduced during the Sb₂O₄/RGO solvothermal preparation process.

Laser Raman scattering is a sensitive and effective method to analyze graphite- and graphene-based materials [21,27]. In Fig. 1b, two major D and G bands appear in the Raman spectra of Sb₂O₄/ RGO-I, Sb₂O₄/RGO-II, Sb₂O₄/RGO-III, RGO and GO. The D and G bands were at approximately 1440 cm⁻¹ and 1591 cm⁻¹, respectively. The D band represents the defective graphitic structure of sp³-bond carbon atoms, while the G band corresponds to the inplace stretching motion of the sp²-bond carbon atoms. The relative intensity ratio (I_D/I_G) manifested the degree of disorder and defects. The corresponding I_D/I_G values of Sb₂O₄/RGO-I, Sb₂O₄/ RGO-II, Sb₂O₄/RGO-III, RGO and GO were 1.12, 1.18, 1.07, 1.01 and 0.99, respectively. We found that the I_D/I_C values of these samples was smaller than Zhou's [9] results. It, possibly because using ethylene glycol and intense magnetic stirring for over 3.5 h to form homogeneous suspensions and somewhat promoted the degree of reduction of the GO and composite. Moreover, disparate systems lead to slight changes. The lowest I_D/I_G value of GO illustrated the highest level of oxidation and regularity. After the solvothermal reaction, the I_D/I_G value increased. Within a certain range,

Download English Version:

https://daneshyari.com/en/article/6471279

Download Persian Version:

https://daneshyari.com/article/6471279

<u>Daneshyari.com</u>